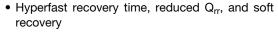


Hyperfast Rectifier, 2 x 10 A FRED Pt®



PRODUCT SUMMARY				
Package	TO-263AC (SMPD)			
I _{F(AV)}	2 x 10 A			
V_{R}	200 V			
V _F at I _F	0.77 V			
t _{rr}	25 ns			
T _J max.	175 °C			
Diode variation	Dual die			

FEATURES





RoHS

COMPLIANT **HALOGEN**

FREE

- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, telecom, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage		V_{RRM}		200	V
Average rectified forward current per device per diode	per device		T - 152 °C	20	
	I _{F(AV)}	T _{solder pad} = 152 °C	10	۸	
Non-repetitive peak surge current ——	per device	I _{FSM}	T _J = 25 °C, 6 ms square pulse	210	А
	per diode			110	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS MIN. TYP. MAX.		MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	200	-	-	
Farmend valles a resulting	V	I _F = 10 A	-	0.94	1.05	V
Forward voltage, per diode V _F		I _F = 10 A, T _J = 150 °C	-	0.77	0.87	
Reverse leakage current, per diode I _R		$V_R = V_R$ rated	-	-	2	
		T _J = 150 °C, V _R = V _R rated	-	10	150	μΑ
Junction capacitance, per diode	C _T	V _R = 200 V	-	30	-	pF



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNITS
		I _F = 1 A, dI _F /dt = 50 A	Vμs, V _R = 30 V	-	25	-	
Davaga va aayan tima		I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		-	-	25	
Reverse recovery time t _{rr}	L _{rr}	T _J = 25 °C		-	22	-	ns
		T _J = 125 °C		-	35	-	
Dools woods on a suggest		T _J = 25 °C	$I_F = 10 \text{ A},$ $dI_F/dt = 200 \text{ A/}\mu\text{s},$ $V_R = 160 \text{ V}$	-	2.5	-	۸
Peak recovery current	I _{RRM}	T _J = 125 °C		-	5	-	Α
Develope receiver charge	0	T _J = 25 °C		-	25	-	nC
Reverse recovery charge	erse recovery charge Q _{rr}	T _J = 125 °C		-	85	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	+175	°C
Thermal resistance, per diode junction to solder pad	R _{thJ-Sp}		-	1.8	2.4	°C/W
Approximate weight				0.55		g
Approximate weight				0.02		oz.
Marking device		Case style TO-263AC (SMPD)		20CI	DH02	

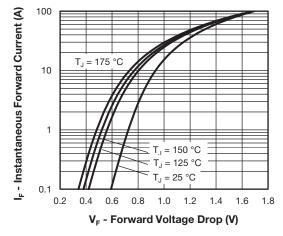


Fig. 1 - Typical Forward Voltage Drop Characteristics

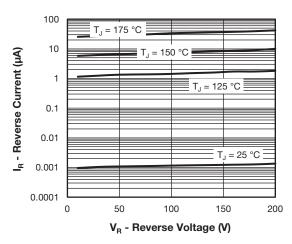


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

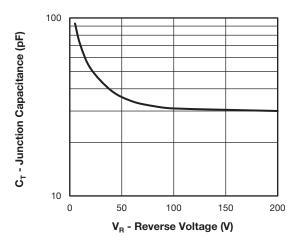


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

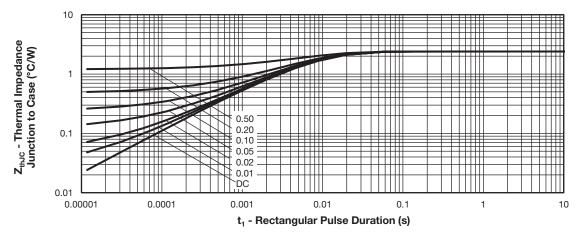


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

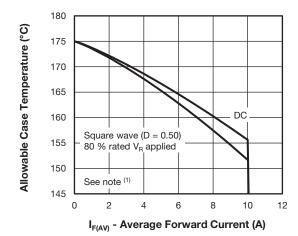


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

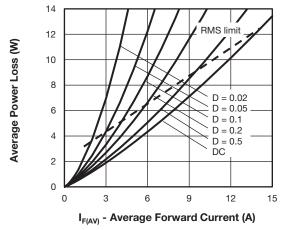


Fig. 6 - Forward Power Loss Characteristics

Note

⁽¹⁾ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 5); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = rated V_R

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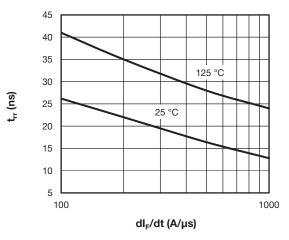


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

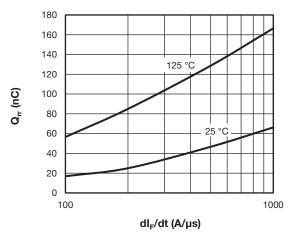
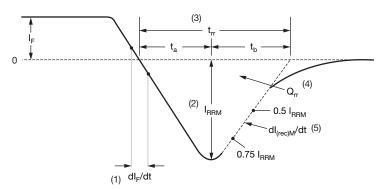


Fig. 8 - Typical Stored Charge vs. dl_F/dt



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm l_{r}$ to point where a line passing through 0.75 $\rm l_{RRM}$ and 0.50 $\rm l_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

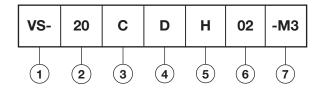
(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (20 A)

3 - Circuit configuration:

C = common cathode

4 - D = SMPD package

5 - Process type,

H = hyperfast recovery

6 - Voltage code (02 = 200 V)

7 - -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

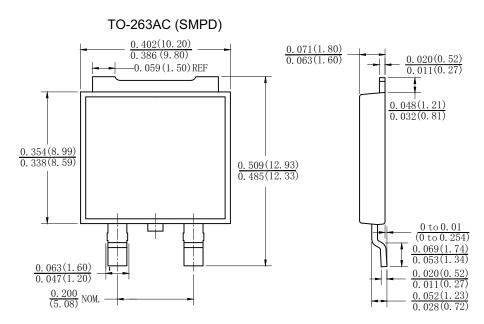
ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-20CDH02-M3/I	2000	2000	13" diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95604</u>				
Part marking information	www.vishay.com/doc?95566			
Packaging information	www.vishay.com/doc?88869			

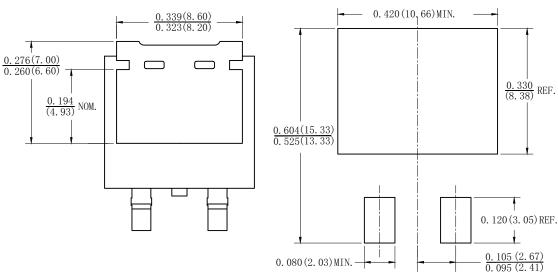


TO-263AC (SMPD)

DIMENSIONS in inches (millimeters)



Mounting Pad Layout





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